MTW [Ga] ZSM-12 Si(93), Ga(7)

Contributed by Susan Lambert

Verified by K. Reddy and M. Mertens

Type Material Na₂[Ga₂Si₂₆O₅₆]: 4 H₂O

Method S. L Lambert [1]

Batch Composition 4.5 Na₂O : Ga₂O₃ : 52.4 SiO₂ : 13.7 TEMA Br : 867 H₂O (TEMA = triethylmethylammonium)

Source Materials

deionized water

sodium hydroxide (Mallinkrodt dry pellets, > 98.5% NaOH)

gallium oxide (Alfa, 99.99%)

triethylmethylammonium bromide (TEMA Br) (Fluka, purum)

silica sol (Dupont Ludox AS-40, 40% Si0₂) a

Batch Preparation (for 13 g dry product)

- (1) [21.72 g NaOH + 37.04 g water + 11.37 g Ga₂O₃], heat in a closed pressure vessel (Teflon-lined Parr acid digestion bomb) at 110°C for 23 hours
- (2) [4.65 g of solution (1) + 29.22 g water + 10.78 g TEMA Br], stir until dissolved
- (3) [(2) + (31.47 g silica sol + 11.63 g H₂O)], add diluted silica sol to (2) with stirring using an eye dropper over course of 15 min. Batch pH 13-14 b

Crystallization

Vessel: two Teflon-lined Parr acid digestion bombs (125 mL)

Time: 20 days ° Temperature: 150°C Agitation: none

Product Recovery

- (1) Supernatant liquid pH 12.5
- (2) Filter and wash with 600 mL distilled water
- (3) Dry at 100°C
- Yield: 13.64 g white solids (12.25 g volatile free), 91% recovery on SiO₂ or 87% on Ga₂O₃

Product Characterization

XRD: MTW framework by comparison to ZSM- 12 crystallinity reference, best is [AI] MTN.

Minor impurity: cristobalite; no other phases present

Elemental Analyses (volatile-free): 93.4% SiO₂, 5.35% Ga₂O₃, 0.62% Na₂O,

0.14%Al₂O₃.

Loss on ignition at 900°C: 10.17% d

Molar Composition: 0.35 Na₂O: 0.05 A1₂O₃: Ga₂O₃: 54.4 SiO₂: 22 H₂O ^e

Reference

[1] S. L Lambert in Proceedings of the 9th international Zeolite Conference, R. von Ballmoos, J. B. Higgins, M. M. J. Treacy (eds.), Butterworth-Heinemann, London, 1993, P. 223

Notes

- a. Dupontâs Ludox HS-40 is an acceptable substitute.
- b. pH values were measured with ColorpHast pH indicator paper (range 5-10 or 7.5-14, from E. M. Science, Gibbstown, NJ, USA)
- c. Crystallinity vs. (Al) ZSM-12 reference: 70% after 16 days, 88% after 18 days, 90% after 20 days. The crystallization proceeds more rapidly as the amount of gallium in the synthesis batch is reduced.
- d. Template burnout occurs at 460°C in air.
- e. By ²⁹Si MAS NMR, Si/(Ga + Al) = 14; excess SiO₂ by elemental analysis is attributed to amorphous silica. ^{7I}Ga static NMR one symmetrical Ga line at 158.5 ppm

(ref. Ga(N0₃)₃).